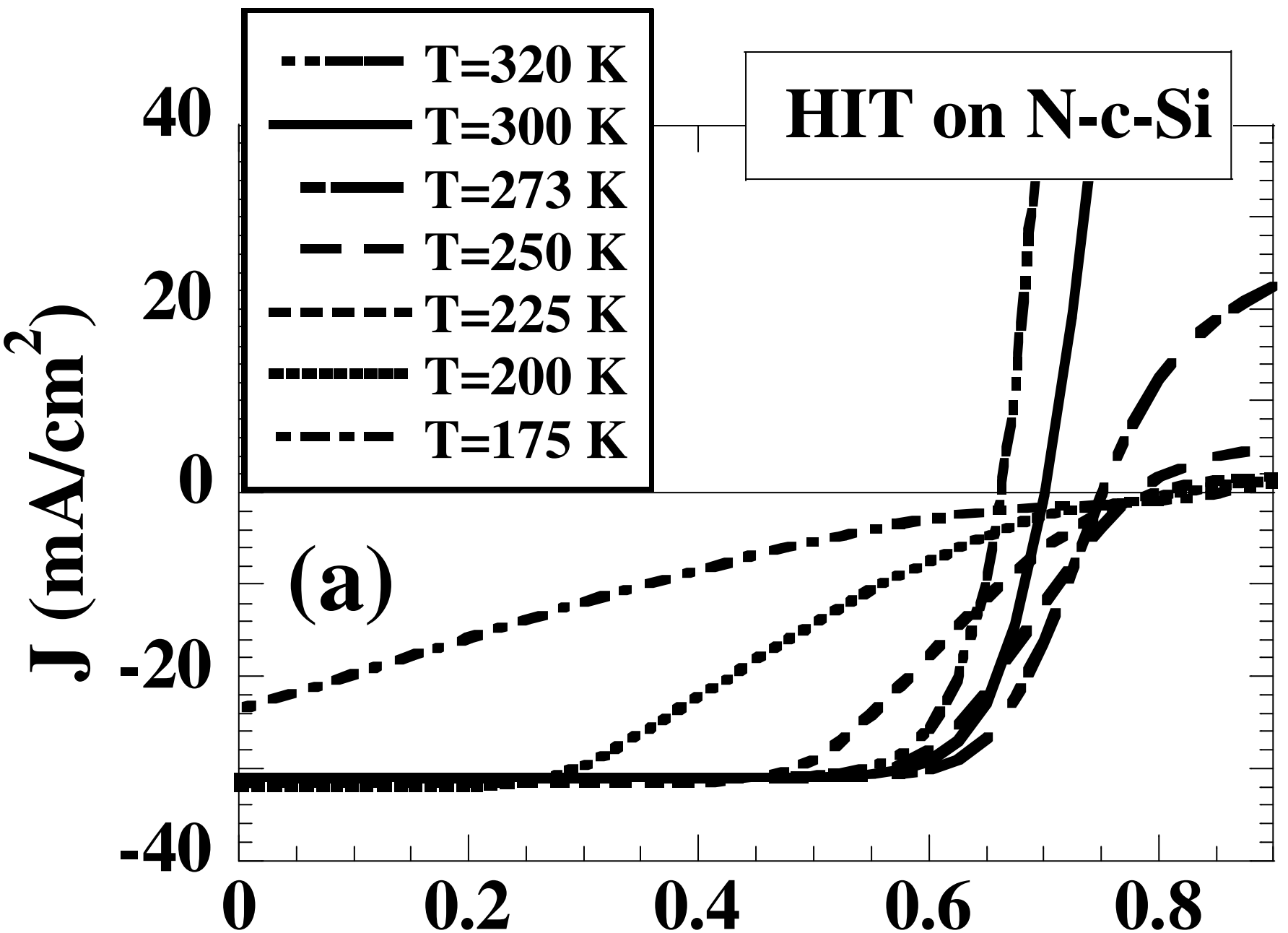
T=320 K
T=300 K
T=273 K
T=250 K
T=225 K
T=200 K
T=175 K
HIT on N-c-Si
(a)
J (mA/cm^2)
40
20
0
-20
-40
0
0.2
0.4
0.6
0.8